威思沃
WISEWORLD

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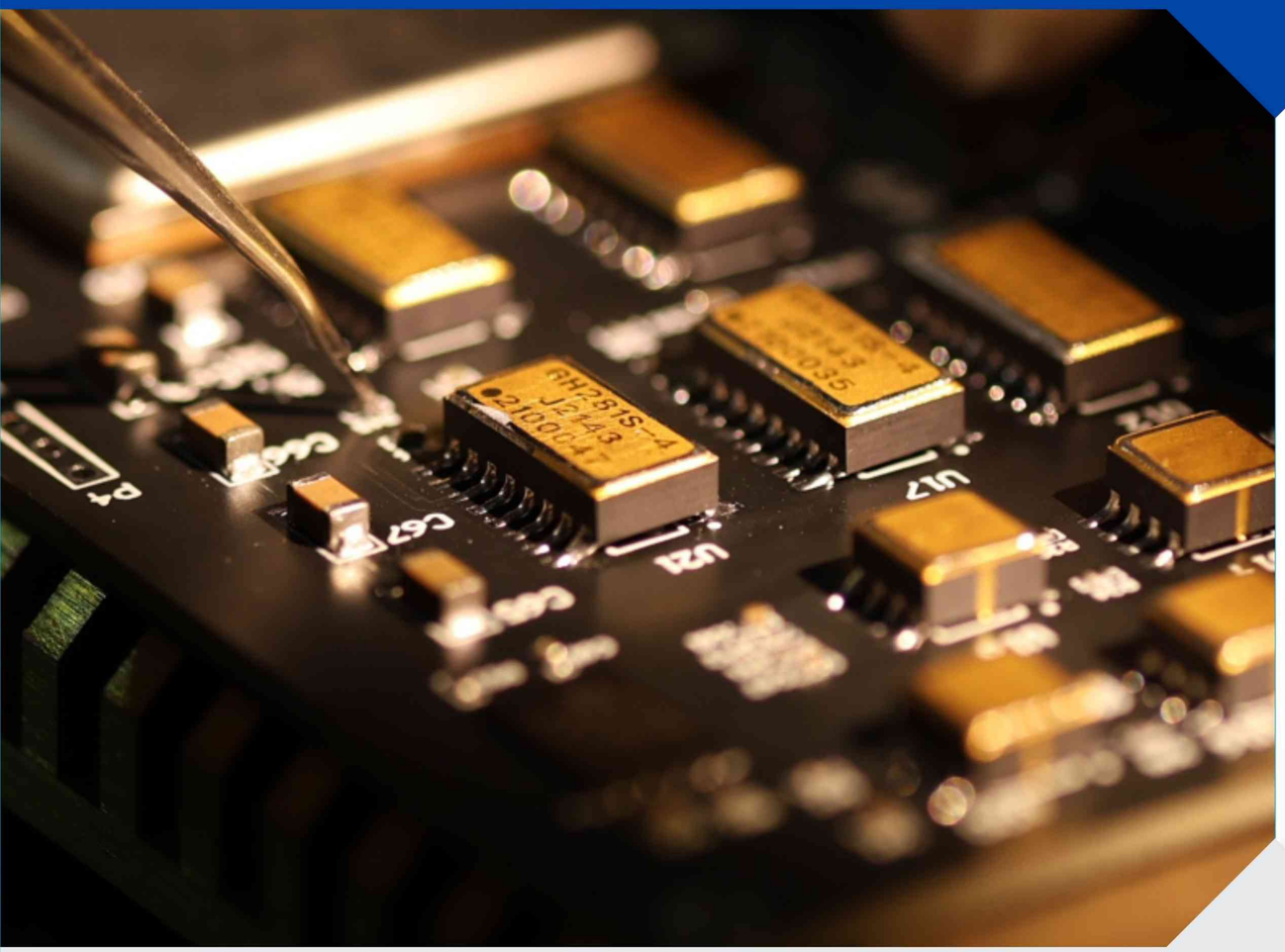
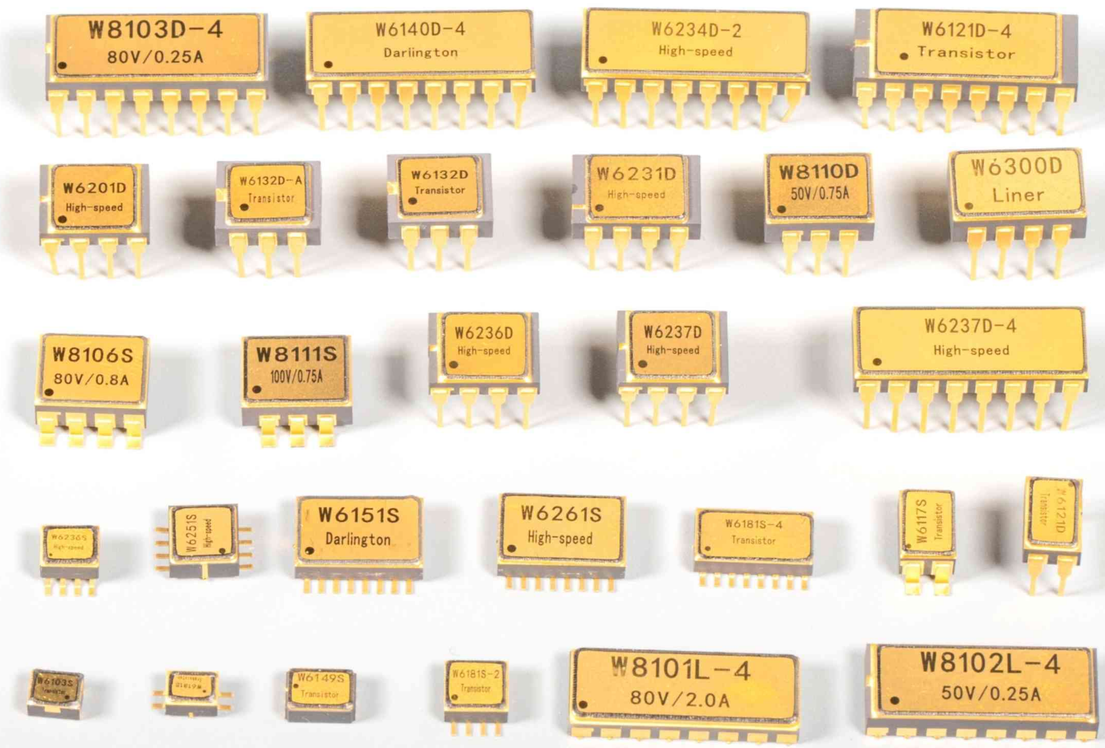
Optocouplers
Optical MOS Solid State Relays





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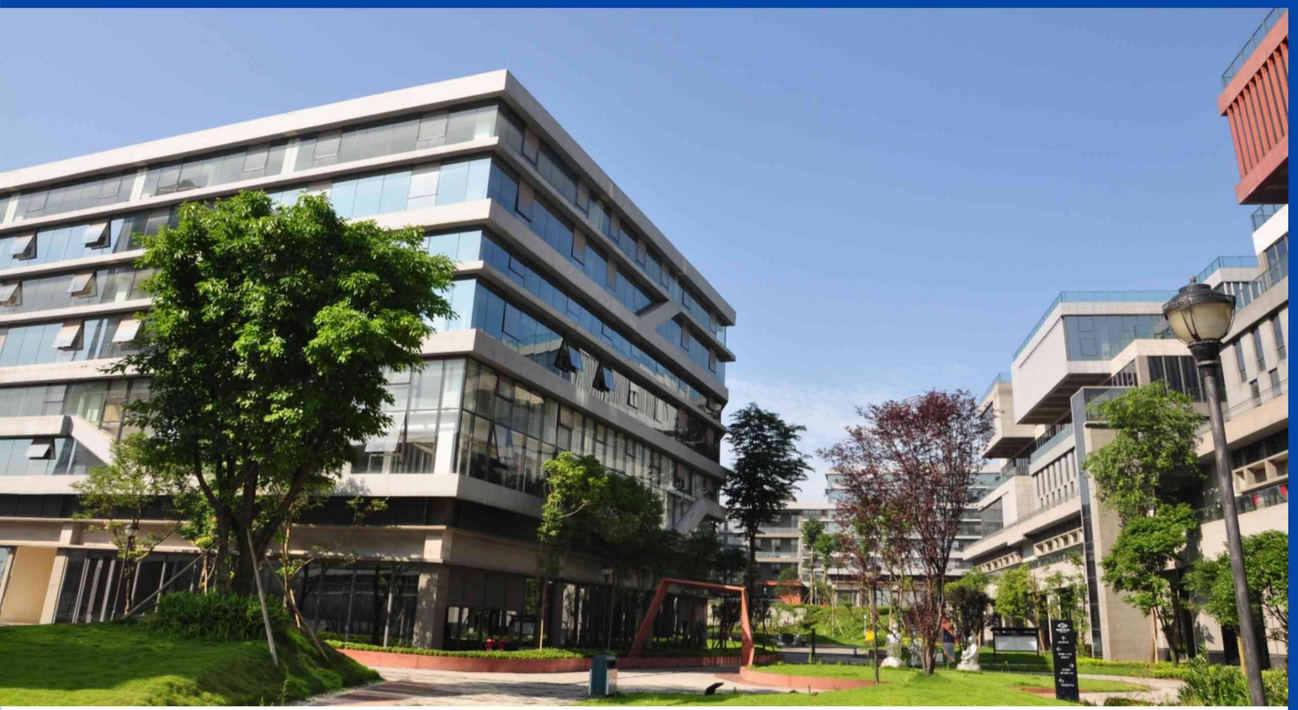
Electronic Circuit with High Reliability and Environmental Adaptability

COMPANY PROFILE



2011
Founding Time

30+
Patents

1000+
Customers

As a nationally recognized Little Giant high-tech enterprise, Wiseworld specializes in cutting-edge photoelectric transmission technologies, including optical couplers, solid-state relays SSR, and microwave photonic components and devices. With a strategic R&D investment exceeding $15 million, we deliver mission-proven solutions for broadband electronic systems and advanced optical communications.

With over 20years experience in the optical transmission products, we has full-spectrum capabilities from R&D to mass production with production capability over 500,000 pcs/year. We are capable of high-precision optoelectronic integration like L/S/C/X/Ku/Ka bands, high-grade packaging such as gas-sealed with high-reliability and advanced microwave photonic systems up to 40GHz. Our products are deployed across rigid platforms including airborne systems, missile guidance, ground vehicles and naval electronics for domestic research institutes who requires high standard quality performance in a wide temperature range with super compact sizes.

Wiseworld will consistently delivers mission-critical reliability to help our customers achieve their objectives and produce superior high-grade products plus best valued prices.

PRODUCT CATALOG

A Optocouplers

01	Transistor	02~04
02	Darlington	05
03	High-speed	06~08
04	Liner	09

B Optical MOS Solid State Relays

01	50V normally open	10~12
02	80V normally open	12~13
03	100V normally open	14~15

Four Core Strengths

01 Excellent High-Temperature Resistance:

Ceramic materials exhibit strong thermal endurance, enabling stable operation in high-temperature environments (typically -55°C to 100°C or higher), making them ideal for industrial high-heat applications.

02 Superior Sealing Performance:

Sealing processes (e.g., welding) between ceramics and metal lids effectively block moisture, dust, and contaminants, offering robust resistance to humidity, mold, and corrosion for extended lifespan.

03 Optimal Thermal Management:

Ceramics provide higher thermal conductivity than plastics, enhancing heat dissipation and minimizing performance degradation under high temperatures.

04 High Stability:

Minimal sensitivity to environmental temperature/humidity fluctuations ensures consistent electrical properties (e.g., isolation voltage, transmission rates), particularly during rapid thermal cycling.

A Optocouplers

Optocouplers

- 01 Transistor
- 02 Darlington
- 03 High-speed
- 04 Liner

FEATURES

1 Mainstream models meet miniaturization requirements; for example, the ceramic SOP-4 package (281 series) reduces dimensions by over 50% compared to conventional sizes.

2 Linear optocoupler with voltage output, featuring nonlinearity <0.5%.

3 Cost-effective solution for budget-sensitive applications, offering lower pricing than competing products from other manufacturers.

4 Diverse quality grades available, including military temperature grade, and industrial grade.

A01 Transistor

W6102S/W6103S/W6111S/W6117S/W6121D/W6121D-2/W6121D-4
W6132D/W6132D-A/W6149S/W6181S/W6181S-2/W6181S-4

W6102S

This product is a single - channel transistor output type photocoupler consisting of an infrared light-emitting diode and a photosensitive transistor, packaged in LCC4 ceramic tube shell. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

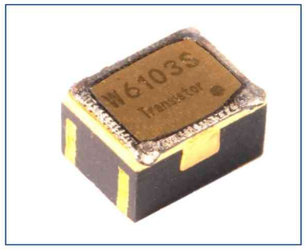
W6102S Dimensions: 6.70x4.40x2.85mm
Packaging: LCC4

Application
- Switching power supply
- Trigger circuit
- Pulse amplifier circuit
- Digital communication circuit

Features
- Isolation voltage: >1000V
- Collector - emitter breakdown voltage: 70V
- Power supply voltage: 1~60V
- Operating temperature: -55°C~+100°C

W6103S

This product is a single - channel transistor output type photocoupler consisting of an infrared light-emitting diode and a photosensitive transistor, packaged in LCC4 ceramic tube shell. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.



W6103S Dimensions: 4.70x3.70x2.80mm
Packaging: LCC4

Application
- Switching power supply
- Trigger circuit
- Pulse amplifier circuit
- Digital communication circuit
- Computer interface circuit

Features
- Isolation voltage: >1000V
- Collector - emitter breakdown voltage: 70V
- Power supply voltage: 1~60V
- Operating temperature: -55°C~+100°C

W6111S W6117S W6121D W6132D W6132D-A W6149S W6181S

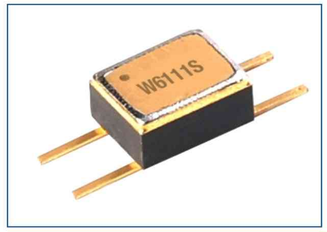
This product is a single - channel transistor output type photocoupler composed of an infrared light-emitting diode and a photosensitive transistor. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application

Switching power supply
Trigger circuit
Pulse amplifying circuit
Digital communication circuit
Computer interface circuit

Features

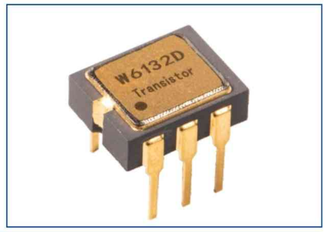
Isolation voltage: >1000V
Collector-emitter breakdown voltage: 70V
Power supply voltage: 1~60V
Operating temperature: -55°C~+100°C



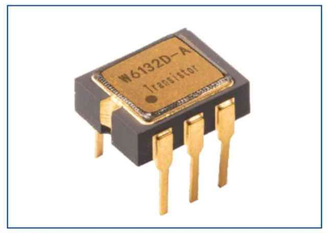
W6111S
Dimensions: 5.70x4.30x3.00mm
Packaging: SOP4

W6117S
Dimensions: 7.10x5.20x3.60mm
Packaging: SOP4

W6121D
Dimensions: 5.20x7.62x3.70mm
Packaging: DIP4

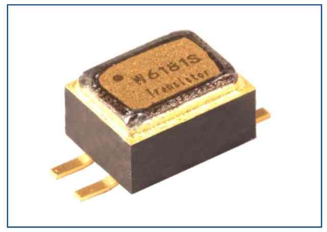


W6132D
Dimensions: 9.55x7.62x4.20mm
Packaging: DIP6



W6132D - A
Dimensions: 9.55x7.62x4.20mm
Packaging: DIP6

W6149S
Dimensions: 6.46x4.58x2.90mm
Packaging: LCC6



W6181S
Dimensions: 4.90x3.80x2.90mm
Packaging: SOP4

A01 Transistor W6102S/W6103S/W6111S/W6117S/W6121D/W6121D-2/W6121D-4 W6132D/W6132D-A/W6149S/W6181S/W6181S-2/W6181S-4

W6121D-2 W6181S-2

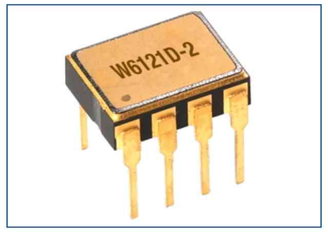
This product is a dual - channel transistor output type optocoupler composed of two infrared light-emitting diodes and two photosensitive transistors. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application

Switching power supply
Trigger circuit
Pulse amplifier circuit
Digital communication circuit
Computer interface circuit

Features

Isolation voltage: >1000V
Collector - emitter breakdown voltage: 70V
Power supply voltage: 1~60V
Operating temperature: -55°C~+100°C



W6121D-2
Dimensions: 5.70x5.20x2.90mm
Packaging: SOP8

W6181S-2
Dimensions: 12.16x7.62x3.80mm
Packaging: DIP8

W6121D-4 W6181S-4

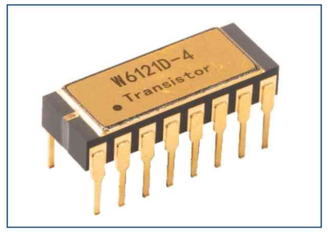
This product is a four - channel transistor output type photocoupler composed of four infrared light-emitting diodes and four photosensitive transistors. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application

Switching power supply
Trigger circuit
Pulse amplifier circuit
Digital communication circuit
Computer interface circuit

Features

Isolation voltage: >1000V
Collector - emitter breakdown voltage: 70V
Power supply voltage: 1~60V
Operating temperature: -55°C~+100°C



W6121D-4
Dimensions: 20.60x7.62x4.00mm
Packaging: DIP16

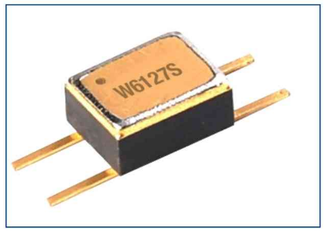
W6181S-4
Dimensions: 10.90x5.80x2.80mm
Packaging: SOP16

A02 Darlington

W6127S/W6132D-B/W6140D-4/W6151S

W6127S
W6132D-B

This product is a single - channel Darlington output type photocoupler consisting of an infrared light - emitting diode and a photosensitive processing chip. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.



W6127S Dimensions: 5.70x4.30x3.00mm
Packaging: SOP4

Application
Switching power supply
Trigger circuit
Pulse amplifier circuit
Computer interface circuit

Features
Isolation voltage: >1000V
Collector - emitter breakdown voltage: >300V
Low drive current: 0.5mA
Operating temperature: -55°C~+100°C

W6132D-B Dimensions: 9.55x7.62x4.2mm
Packaging: DIP6

Application
Switching power supply
Trigger circuit
Pulse amplifier circuit
Digital communication circuit
Computer interface circuit

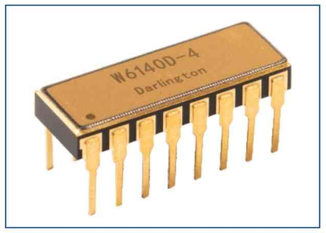
Features
Isolation voltage: >1000V
Collector - emitter breakdown voltage: >300V
Power supply voltage: 2~200V
Low drive current: 0.5mA
Operating temperature: -55°C~+100°C

W6140D-4
W6151S

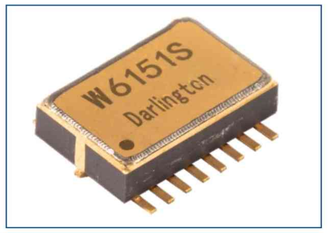
This product is a four - channel Darlington output optocoupler composed of four infrared light - emitting diodes and four photosensitive processing chips, SOP16 ceramic tube package. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application
Switching power supply
Trigger circuit
Pulse amplifier circuit
Digital communication circuit
Computer interface circuit

Features
Isolation voltage: >1000V
Collector - emitter breakdown voltage: >300V
Power supply voltage: 2~200V
Low drive current: 0.5mA
Operating temperature: -55°C~+100°C



W6140D - 4
Dimensions: 20.90x7.62x3.60mm
Packaging: DIP16



W6151S
Dimensions: 11.40x7.30x2.80mm
Packaging: SOP16

A03 High-speed

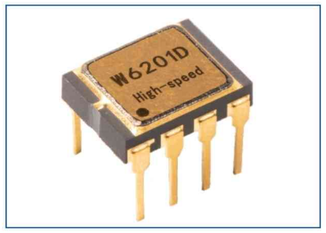
W6201D/W6231D/W6231S/W6234D-2/W6236D/W6236S/
W6237D/W6237D-4/W6251D/W6251S/W6261S

W6201D

This product is a single - channel totem pole output type photocoupler consisting of an infrared light - emitting diode and a photosensitive processing chip, packaged in DIP8 ceramic tube shell. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application
A/D, D/A conversion digital isolation
Computer interface circuit
Microsystem interface circuit
High - speed logic circuit
Level conversion
Instrument input and output isolation
Ground loop elimination
Pulse transformer replacement

Features
Isolation voltage: >1000V
Power supply voltage: 4.5V~20V
Totem pole output in phase
Maximum speed: 2Mbit/s
LSTTL/TTL/CMOS compatible
Operating temperature: -55°C~100°C



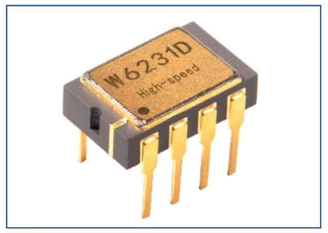
W6201D
Dimensions: 10.50x7.62x3.20mm
Packaging: DIP8

W6231D
W6231S
W6234D - 2

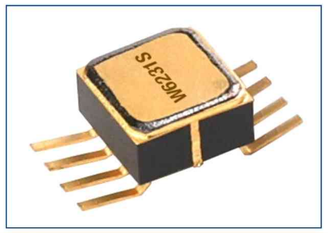
This product is a dual - channel open collector output type photocoupler composed of two infrared light-emitting diodes and two photosensitive processing chips. Working temperature: -55°C ~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application
A/D, D/A conversion digital isolation
Computer interface circuit
Microsystem interface circuit
High - speed logic circuit
Level conversion
Instrument input and output isolation
Ground loop elimination
Pulse transformer replacement

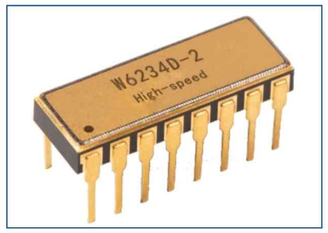
Features
Isolation voltage: >1000V
Power supply voltage: 2.7V~5.5V
Maximum speed: 10Mbit/s
LSTTL/TTL compatible
Operating temperature: -55°C~+100°C



W6231D
Dimensions: 11.70x7.62x3.50mm
Packaging: DIP8



W6231S
Dimensions: 5.40x5.40x3.00mm
Packaging: SOP8



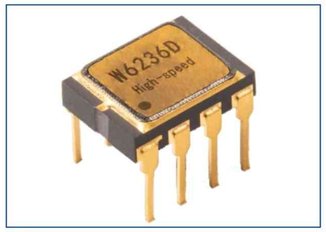
W6234D - 2
Dimensions: 20.90x7.62x3.60mm
Packaging: DIP16

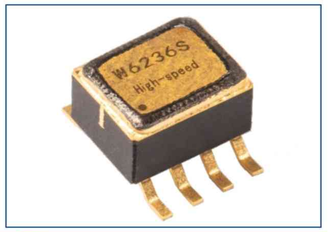
W6236D
W6236S

This product is a single - channel open collector output type photocoupler consisting of an infrared light - emitting diode and a photosensitive processing chip. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application
A/D, D/A conversion digital isolation
Computer interface circuit
Microsystem interface circuit
High - speed logic circuit
Level conversion
Instrument input and output isolation
Ground loop elimination
Pulse transformer replacement

Features
Isolation voltage: >1000V
Power supply voltage: 4.5V~20V
Maximum speed: 1Mbit/s
LSTTL/TTL compatible
Operating temperature: -55°C~+100°C





W6236D
Dimensions: 10.00x7.62x3.00mm
Packaging: DIP8

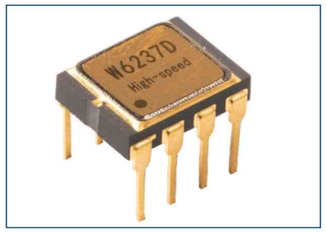
W6236S
Dimensions: 5.40x4.40x3.00mm
Packaging: SOP8

W6237D

This product is a single - channel open collector output type photocoupler consisting of an infrared light - emitting diode and a photosensitive processing chip. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application
A/D, D/A conversion digital isolation
Computer interface circuit
Microsystem interface circuit
High - speed logic circuit
Level conversion
Instrument input and output isolation
Ground loop elimination
Pulse transformer replacement

Features
Isolation voltage: >1000V
Power supply voltage: 2.7V~5.5V
Maximum speed: 10Mbit/s
LSTTL/TTL compatible
Operating temperature: -55°C~+100°C



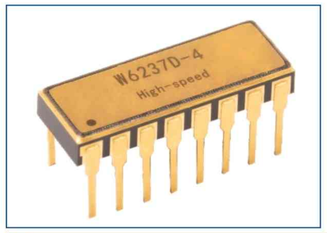
W6237D
Dimensions: 10.00x7.62x3.00mm.
Packaging: DIP8

W6237D-4
W6261S

This product is a four-channel open collector output type photocoupler consisting of four infrared light-emitting diodes and four photosensitive processing chips. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application
A/D, D/A conversion digital isolation
Computer interface circuit
Microsystem interface circuit
High - speed logic circuit
Level conversion
Instrument input and output isolation
Ground loop elimination
Pulse transformer replacement

Features
Isolation voltage: >1000V
Power supply voltage: 2.7V~5.5V
Maximum speed: 10Mbit/s
LSTTL/TTL compatible
Operating temperature: -55°C~+100°C



W6237D-4
Dimensions: 20.90x7.62x3.60mm
Packaging: DIP16

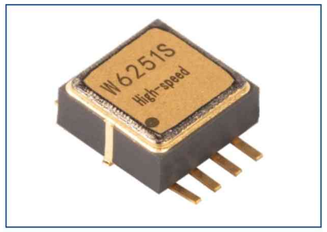
W6261S
Dimensions: 11.40x7.30x2.80mm
Packaging: SOP16

W6251D
W6251S

This product is a dual-channel totem pole output type photocoupler composed of two infrared light-emitting diodes and two photosensitive processing chips. Operating temperature: -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application
A/D, D/A conversion digital isolation
Computer interface circuit
Microsystem interface circuit
High - speed logic circuit
Level conversion
Instrument input and output isolation
Ground loop elimination
Pulse transformer replacement

Features
Isolation voltage: >1000V
Power supply voltage: 4.5V~20V
Totem pole output in phase
Maximum speed: 2Mbit/s
LSTTL/TTL/CMOS compatible
Operating temperature: -55°C~+100°C



W6251D
Dimensions: 11.90x7.62x3.30mm
Packaging: DIP8

W6251S
Dimensions: 6.10x6.10x3.20mm
Packaging: SOP8

A04 Liner W6300D/W6301S/W6302S/W6303S

W6300D

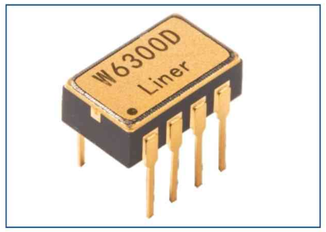
This product is a single - channel current output linear optocoupler composed of an infrared light - emitting diode and two photosensitive transistors, packaged in DIP8 ceramic tube shell. The transfer coefficient is 1, and the operating temperature is -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

Application

Power supply feedback voltage and current
Medical sensor signal isolation
Automatic signal bonding
Isolated process control sensor
Digital telephone isolation

Features

Isolation voltage: >1000V
Non - linearity: □1%
Transfer coefficient: 1.0±0.1
Static level: 1000V
Operating temperature: -55°C~+100°C



W6300D

Dimensions: 12.20x7.62x4.40mm
Packaging: DIP8

W6301S
W6302S
W6303S

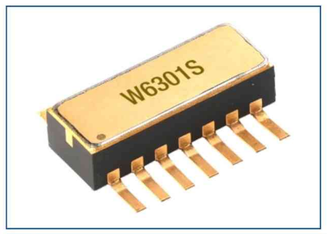
This product is a single - channel voltage output linear optocoupler composed of an infrared light - emitting diode, a triode, two photosensitive transistors and two operational amplifier chips. Operating temperature is -55°C~+100°C, meeting the application requirements of high reliability and environmental adaptability.

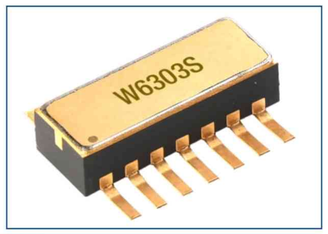
Application

Power supply feedback voltage and current
Sensor signal isolation
Audio signal bonding
Isolated process control sensor
Motor drive circuit

Features

Isolation voltage: 1000V
Static level: 1000V





W6301S

Nonlinearity: ≤0.5%
Transfer coefficient: 1.0±0.05

Dimensions: 19.80x7.70x5.00mm
Packaging: SOP14

W6302S

Nonlinearity: ≤1%
Transfer coefficient: 0.5±0.05

Dimensions: 19.80x7.70x5.00mm
Packaging: SOP14

W6303S

Nonlinearity: ≤1%
Transfer coefficient: 0.2±0.01

Dimensions: 19.80x7.70x5.00mm
SOP14

B Optical MOS Solid State Relays

Optical MOS Solid State Relays

01 50V normally open
02 80V normally open
03 100V normally open

FEATURES

1, Mainstream models meet the requirements of miniaturized applications, with dimensions over 1/3 smaller than conventional sizes.

2, Meet the requirements of high-reliability applications, with a chip sintering void rate of <3%.

3, Meet the requirements of low-cost applications, with prices lower than those of similar products from other manufacturers.

4, Diverse quality grades available, including military-grade, military temperature-grade, and industrial-grade products.

B01 50V normally open W8110D/W8113D/W8104D-2/W8105L-2/W8115D-2/W8116D/W114S

W8110D
W8113D

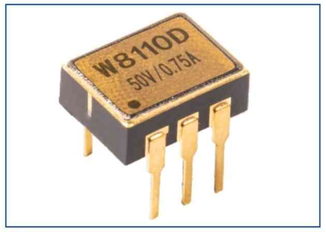
This product is a normally open MOS solid relay consisting of an infrared light emitting diode, a photovoltaic chip, and two MOS tubes, packaged in DIP6 ceramic tube shell. The maximum output voltage is 50V, and the operating temperature is -55°C~+105°C, meeting the application requirements of high reliability and environmental adaptability.

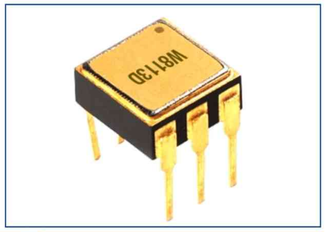
Application

Signal isolation
Switching circuit
Motor drive circuit
Ignition control circuit
Replace pulse transformer

Features

Bidirectional configuration/unidirectional configuration
Output stage normally open type
Maximum output voltage: 50V
Operating temperature: -55°C~+105°C





W8110D

Maximum output on-resistance: 1Ω
Rated output current: 0.75A

Dimensions: 9.70x7.62x3.90mm
Packaging: DIP6

W8113D

Maximum output on - resistance: 0.2/0.3Ω
Rated output current: 2A/1A

Dimensions: 9.70x7.62x3.60mm
Packaging: DIP6

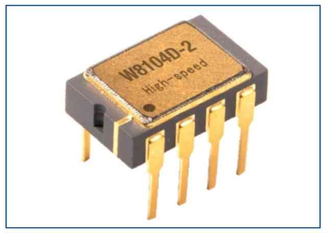
B01 50V normally open W8110D/W8113D/W8104D-2/W8105L-2/W8115D-2/W8116D/W114S

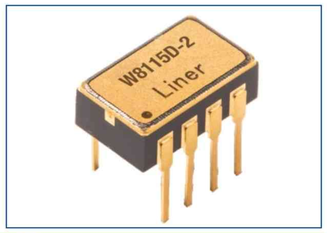
W8104D-2
W8105L-2
W8115D-2

This product is two sets of two-way normal open MOS solid relays consisting of two infrared light-emitting diodes, two photovoltaic chips, and four MOS tubes. Operating temperature is -55°C~+105°C, meeting the application requirements of high reliability and environmental adaptability.

Application
Signal isolation
Switching circuit
Motor drive circuit
Ignition control circuit
Replace pulse transformer

Features
Bidirectional configuration
Output stage normally open type
Operating temperature: -55°C~+105°C





W8104D-2
Maximum output voltage: 60V
Maximum output on-resistance: 1Ω
Rated output current: 0.3A

Dimensions: 7.62x5.20x3.70mm
Packaging: DIP4

W8105L-2
Maximum output voltage: 60V
Maximum output on-resistance: 1Ω
Rated output current: 0.3A

Dimensions: 9.70x7.40x2.90mm
Packaging: SMD8

W8115D-2
Maximum output voltage: 55V
Maximum output on-resistance: 0.22Ω
Rated output current: 1.5A

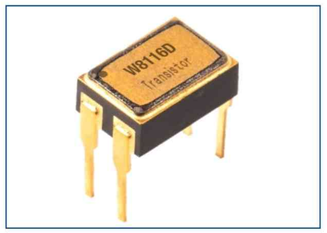
Dimensions: 19.46x10.16x3.90mm
Packaging: DIP8

W8116D

This product is one set of two-way normal open MOS solid relay consisting of an infrared light emitting diode, a photovoltaic chip, and two MOS tubes. Operating temperature is -55°C~+105°C, meeting the application requirements of high reliability and environmental adaptability.

Application
Signal isolation
Switching circuit
Motor drive circuit
Ignition control circuit
Replace pulse transformer

Features
Bidirectional configuration
Output stage normally open type
Maximum output voltage: 50V
Maximum output on-resistance: 2Ω
Rated output current: 0.3A
Operating temperature: -55°C~+105°C



W8116D
Dimensions: 7.62x5.20x3.70mm
Packaging: DIP4

B01 50V normally open W8110D/W8113D/W8104D-2/W8105L-2/W8115D-2/W8116D/W114S

W8114S

This product is one set of one/two-way normal open MOS solid relay consisting of an infrared light emitting diode, a photovoltaic chip, and two MOS tubes, packaged in CSOP6 ceramic tube shell. The maximum output voltage is 50V, the rated output current is 2A/1A, and the operating temperature is -55°C~+105°C, meeting the application requirements of high reliability and environmental adaptability.

Application
Signal isolation
Switching circuit
Motor drive circuit
Replace pulse transformer

Features
Bidirectional configuration/unidirectional configuration
Output stage normally open type
Maximum output voltage: 50VIgnition control circuit
Maximum output on-resistance: 0.3Ω
Rated output current: 2A/1A

W8114S
Dimensions:9.70mm7.37mm3.60mm
Packaging: CSOP6

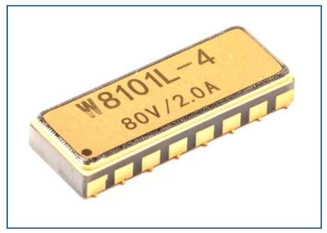
B02 80V normally open W8101L-4/W8106L/W8106S/W8109L

W8101L-4

This product is four sets of two-way normal open MOS solid relays consisting of four infrared light-emitting diodes, four photovoltaic chips, and eight MOS tubes, and is packaged in SMD16 ceramic tube shell. The maximum output voltage is 90V, the rated output current is 2A, and the operating temperature is -55°C~+105°C, meeting the application requirements of high reliability and environmental adaptability.

Application
Signal isolation
Switching circuit
Ignition control circuit
Replace pulse transformer

Features
Bidirectional configuration
Output stage normally open type
Maximum output voltage: 90V
Maximum output on-resistance: 0.15Ω
Rated output current: 2A
Operating temperature: -55°C~+105°C



W8101L-4
Dimensions: 20x7.4x3.6mm
Packaging: SMD16

B02 80V normally open W8101L-4/W8106L/W8106S/W8109L

W8106L
W8106S
W8109L

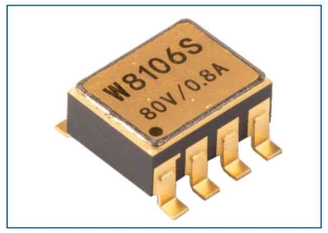
This product is one set of one/two-way normal open MOS solid relay consisting of two infrared light emitting diodes, two photovoltaic chips, and two MOS tubes. The maximum output voltage is 85V, and the operating temperature is -55°C~+105°C, meeting the application requirements of high reliability and environmental adaptability.

W8106L

Dimensions: 9.70x7.62x3.80mm
Packaging: DIP8

Application
Signal isolation
Switching circuit
Motor drive circuit
Ignition control circuit
Replace pulse transformer

Features
Bidirectional configuration/unidirectional configuration
Output stage normally open type
Maximum output voltage: 85V
Maximum output on-resistance: 0.13/0.5Ω
Rated output current: 1.6/0.8A
Operating temperature: -55°C~+105°C

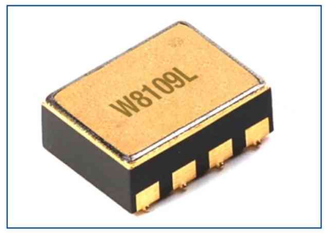


W8106S

Dimensions: 9.70x5.70x3.70mm
Packaging: CSOP8

Application
Signal isolation
Switching circuit
Motor drive circuit
Replace pulse transformer

Features
Bidirectional configuration/unidirectional configuration
Output stage normally open type Ignition control circuit
Maximum output voltage: 85V
Maximum output on-resistance: 0.13/0.5Ω
Rated output current: 1.6/0.8A
Operating temperature: -55°C~+105°C



W8109L

Dimensions: 9.70x7.40x2.90mm
Packaging: SMD8

Application
Signal isolation
Switching circuit
Motor drive circuit
Ignition control circuit
Replace pulse transformer

Features
Bidirectional configuration
Output stage normally open type
Maximum output voltage: 85V
Maximum output on-resistance: 0.03/0.12Ω
Rated output current: 5A/2.5A
Operating temperature: -55°C~+105°C

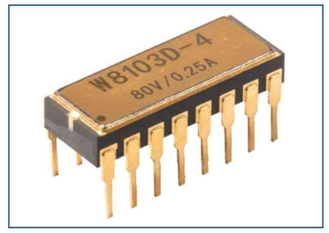
B03 100V normally open W8102L-4/W8103D-4/W8111S/W8112D-2

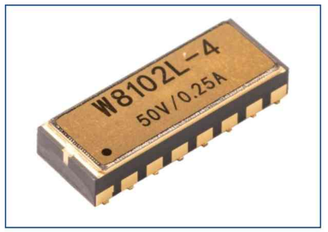
W8103D-4
W8102L-4

This product is four sets of two-way normal open MOS solid relays consisting of four infrared light-emitting diodes, four photovoltaic chips, and eight MOS tubes. The maximum output voltage is 100V, the rated output current is 0.25A, and the operating temperature is -55°C~+105°C, meeting the application requirements of high reliability and environmental adaptability.

Application
Signal isolation
Switching circuit
Motor drive circuit
Ignition control circuit
Replace pulse transformer

Features
Bidirectional configuration
Output stage normally open type
Maximum output voltage: 100V
Maximum output on-resistance: 1.5Ω
Rated output current: 0.25A
Operating temperature: -55°C~+105°C





W8103D-4

Dimensions: 20.00x7.40x3.60mm
Packaging: DIP16

W8102L-4

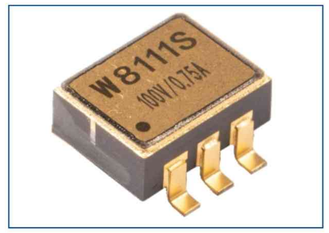
Dimensions: 20.00x7.40x3.60mm
Packaging: SMD16

W8111S

This product is one set of two-way normal open MOS solid relay consisting of an infrared light emitting diode, a photovoltaic chip, and two MOS tubes, packaged in CSOP6 ceramic tube shell. The maximum output voltage is 100V, the rated output current is 0.75A, and the operating temperature is -55°C~+105°C, meeting the application requirements of high reliability and environmental adaptability.

Application
Signal isolation
Switching circuit
Motor drive circuit
Ignition control circuit
Replace pulse transformer

Features
Bidirectional configuration
Output stage normally open type
Maximum output voltage: 100V
Maximum output on-resistance: 0.8Ω
Rated output current: 0.75A
Operating temperature: -55°C~+105°C



W8111S

Dimensions: 9.70x7.37x3.60mm
Packaging: CSOP6

B03 100V normally open W8102L-4/W8103D-4/W8111S/W8112D-2

W8112D-2

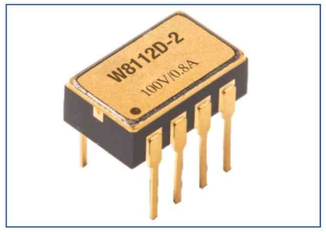
This product is two sets of two-way normal open MOS solid relays consisting of two infrared light-emitting diodes, two photovoltaic chips, and four MOS tubes, and is packaged in DIP8 ceramic tube shell. The maximum output voltage is 100V, the rated output current is 0.8A, and the operating temperature is -55°C~+105°C, meeting the application requirements of high reliability and environmental adaptability.

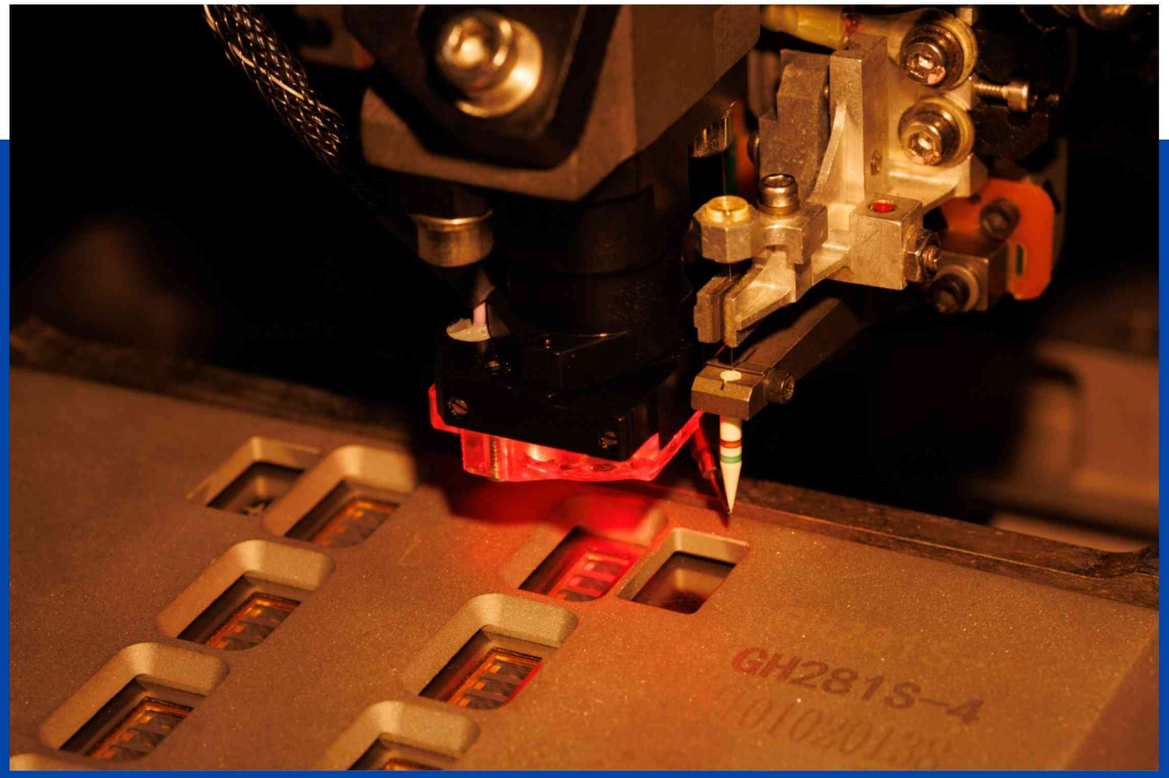
Application

Signal isolation
Switching circuit
Motor drive circuit
Ignition control circuit
Replace pulse transformer

Features

Bidirectional configuration
Output stage normally open type
Maximum output voltage: 100V
Maximum output on-resistance: 1Ω
Rated output current: 0.8A
Operating temperature: -55°C~+105°C



W8112D-2

Dimensions: 19.46x10.16x3.90mm
Packaging: DIP8